

MOSFET Current versus Voltage with Linearized Depletion Charge

The inversion charge is given by:

$$Q'_I(y) = - [V_{GB} - V_{FB} - (V_{CB}(y) - 2\phi_F)] C'_{ox} - Q'_B(y). \quad (1)$$

Rather than using

$$Q'_B(y) = \mp q N_B x_{d\max}(y) = \mp \sqrt{2K_s \epsilon_0 q N_B |V_{CB}(y) - 2\phi_F|}, \quad (2)$$

we can instead approximate $Q'_B(y)$ by its first order Taylor series around $V_{CB} = V_{SB}$:

$$\begin{aligned} Q'_B(y) &\cong Q'_B(0) + V_{CS} (dQ'_B(y)/dV_{CB})_{V_{SB}} \\ &= \mp \sqrt{2K_s \epsilon_0 q N_B |V_{SB}(y) - 2\phi_F|} - V_{CS} \sqrt{\frac{K_s \epsilon_0 q N_B}{2|V_{SB}(y) - 2\phi_F|}} \end{aligned} \quad (3)$$

Thus,

$$Q'_I(y) = - [V_{GS} - V_{th} - (1 + \alpha)V_{CS}(y)] C'_{ox}, \quad (4)$$

where

$$\alpha = \frac{1}{C'_{ox}} \sqrt{\frac{K_s \epsilon_0 q N_B}{2|V_{SB} - 2\phi_F|}} = \frac{C'_d}{C'_{ox}} \quad (5)$$

Integrating from $y = 0$ to L and $V_{CS} = 0$ to V_{DS} ,

$$I_{DS} = \pm \frac{W}{L} \mu' C'_{ox} \left[V_{GS} - V_{th} - (1 + \alpha) \frac{V_{DS}}{2} \right] V_{DS} \quad (6)$$

where V_{th} includes the effects of ϕ_F , ϕ_{MS} , oxide charges and $Q'_B(y = 0)$.

For a typical device, the approximate expression (6) works well in capturing the effect of changing depletion charge. For large V_{DS} , a slightly smaller value of α based on expanding V_{CB} around a value between V_{DB} and V_{SB} may be better.

Equation (6) is only valid when an inversion layer exists all the way across the channel from the source to the drain. As V_{DS} increases, the voltage between the gate and the channel near the drain decreases until it is less than V_{th} , pinching off the channel. This occurs when

$$V_{DS} > \frac{V_{GS} - V_{th}}{1 + \alpha} = V_{DS\text{sat}}. \quad (7)$$

When V_{DS} exceeds the saturation voltage, a channel no longer exist all the way to the drain. This is known as the saturation or ‘‘pinch-off’’ region. Additional voltage is dropped across a narrow depleted (not inverted) region near the drain and the drain current remains near its maximum value:

$$I_{DS\text{sat}} = \pm \frac{W}{L} \mu' C'_{ox} \left[\frac{(V_{GS} - V_{th})^2}{2(1 + \alpha)} \right] \quad (8)$$